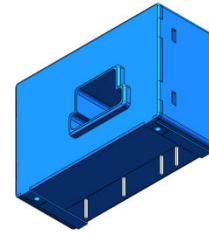


Hall effect Current Sensor

SCB31



Product description

Features

- Based on Hall effect measurement principle, close loop circuit mode.
- The isolation voltage between primary and secondary is greater than 3000VAC.
- Comply with UL94-V0 flame retardant rating.

Performance

- It can measure DC, AC, pulse, and various irregular waveform currents of cable conductors under isolation conditions.
- Very low temperature drift, zero drift, fast response time, good linearity, accuracy can reach 0.1%.
- Dynamic performance (di/dt and response time) is optimal when the busbar is fully filled with primary perforations.
- Strong ability to resist external electromagnetic interference (BCI, EFT, CS, CE, ESD, dv/dt, etc.).

Application

- It can be widely used in inverters, UPS, photovoltaic inverters, electric vehicle drives, high-frequency power supplies, inverter welding machines and other products.

Implementation standards

- GB/T 7665-2005
- JB/T 7490-2007
- JB/T 25480-2010
- JB/T 9473-2020
- SJ 20792-2000

Certification



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Technical Parameters

Model Parameters (25℃)	SCB31-	
	100A	200A
Primary Current (A) I_{PN}	100A	200A
Primary Current Max. Peak Value (A) I_{PM}	±200A	±300A
Turns ratio K_N	1:2000	1:2000
Secondary coil internal resistance R_S @ $T_A=70^\circ\text{C}$	76Ω	76Ω
Output signal I_{SN} @ I_{PN} ,	±50mA	±100mA
Measure resistance R_M @ I_{PN} , $V_C=\pm 15\text{V}$,	20~80Ω	12~70Ω

Electrical Data

Item	Min.	Typical	Max.	Unit
Input power supply voltage range V_C (±5%) (Remark 1, Remark 2)	±12	±15	±18	V _{DC}
Current consumption I_C @ ±15V	13mA+Output Current I_S			mA
Accuracy X @ I_{PN} , $T_A=25^\circ\text{C}$	-	±0.5	±0.8	%
Linearity ε_L @ $R_L=10\text{K}\Omega$, $T_A=25^\circ\text{C}$	-	±0.1	±0.5	%
Offset current I_{OE} @ $T_A=25^\circ\text{C}$, $I_P=0$	-	±0.2	±0.5	mA
Magnetic offset current I_{OM} @ $I_P \rightarrow 0$	-	±0.2	±0.5	mA
Temperature coefficient of offset current TCI_{OE}	-	±0.2	±1	mA
Response time t_D @ $0 \rightarrow I_{PN}$	-	1	-	us
Band width BW	-	50	100K	Hz
Ambient operating temperature T_A	-40	25	85	℃
Ambient storage temperature T_s	-40	25	90	℃
Withstand voltage V_D @ 50Hz, 60s, 0.1mA	-	3000	-	V _{AC}
Weight m	-	40	-	g

Remarks:

1. V_C is greater than the maximum value, which may cause permanent failure of the measurement

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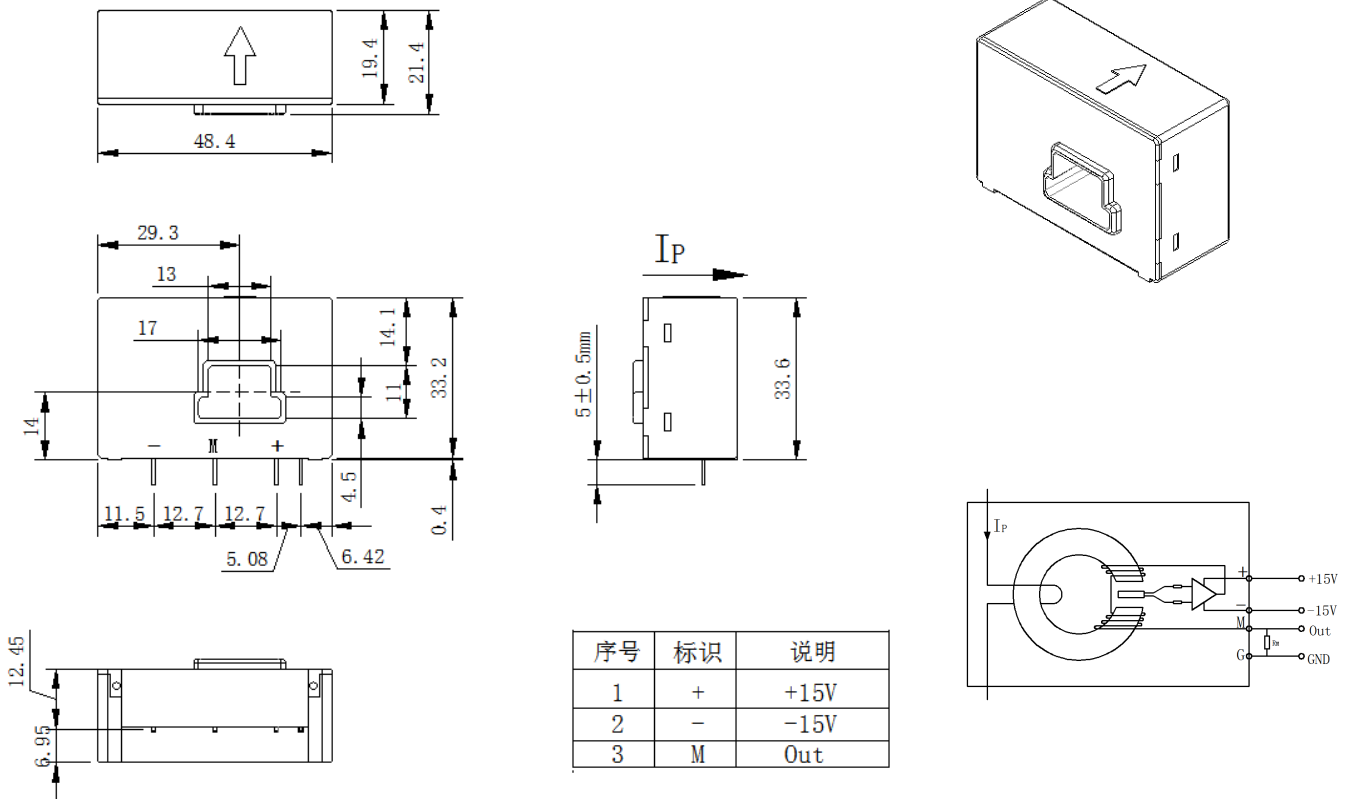
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device.

$$2. I_{OUT} = I_{SN} * \frac{I_P}{I_{PN}} + I_{OE}$$

3. Follow speed $di/dt > 100A/uS$

Dimensions (in mm)



Notes:

1. Size error: $\pm 0.5mm$;
2. Primary aperture: $\square 17*4.5+13*6.5mm$;
3. Pinpoint output: $\square 0.64*0.56mm*4$,

Recommended PCB cut-out: 0.9mm;

4. The IP indication direction is the positive direction of the current;
5. Incorrect wiring may cause damage to the sensor.

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